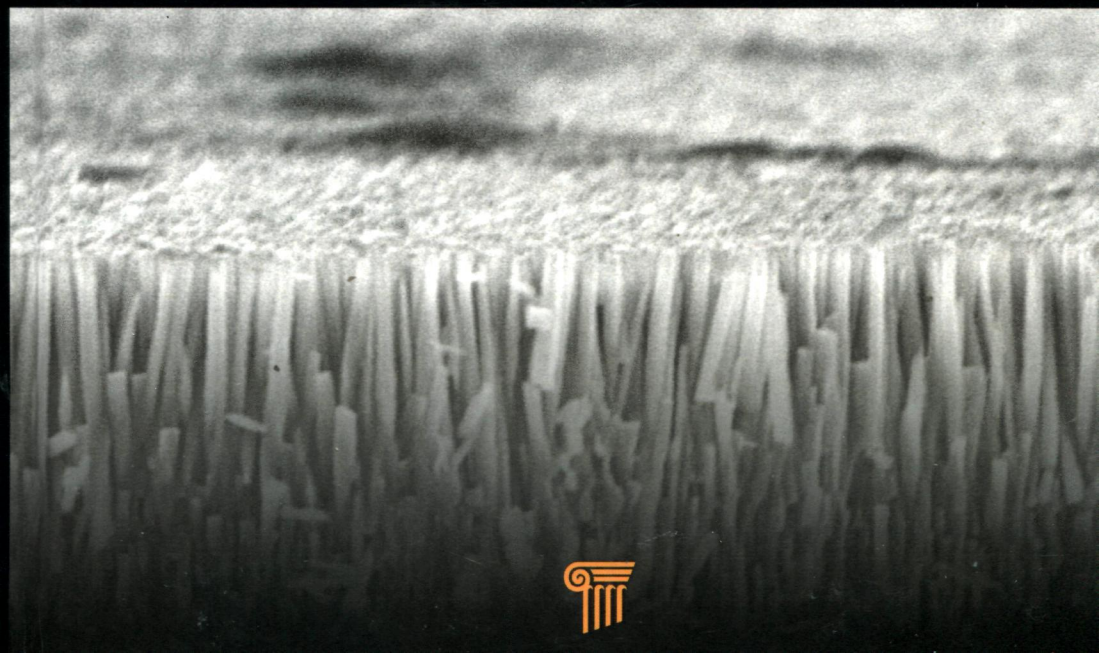


# ZnO Nanostructures and Their Applications

Xiao Wei Sun and Yi Yang



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